

Structures Report

Reinaldo Zapata

1 Up

1.1 \mathcal{V}^{xb} energy range 0.0–0.2 eV

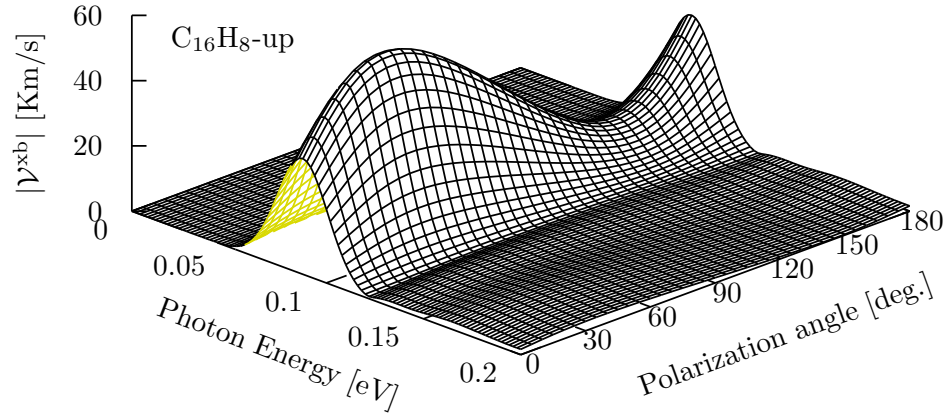


Figure 1: The most intense response for \mathcal{V}^{xb} is for 40°.

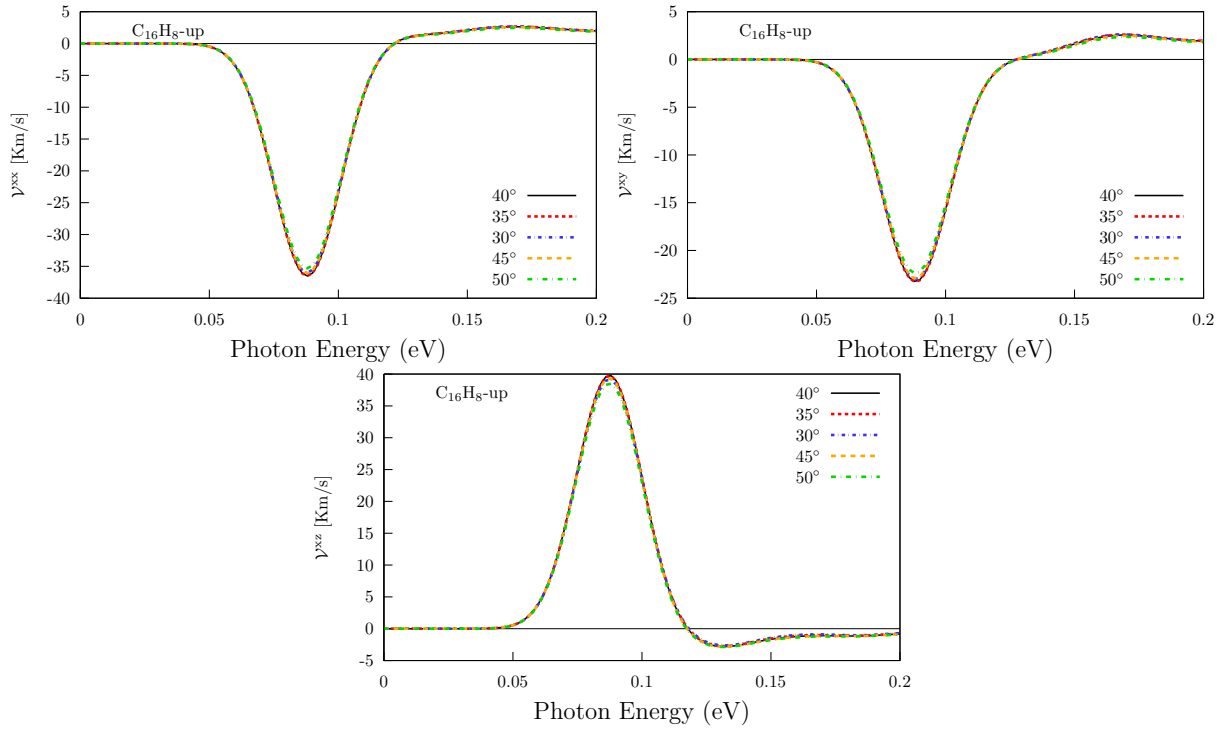


Figure 2: Cheking angle of incidence for xb components for up structure.

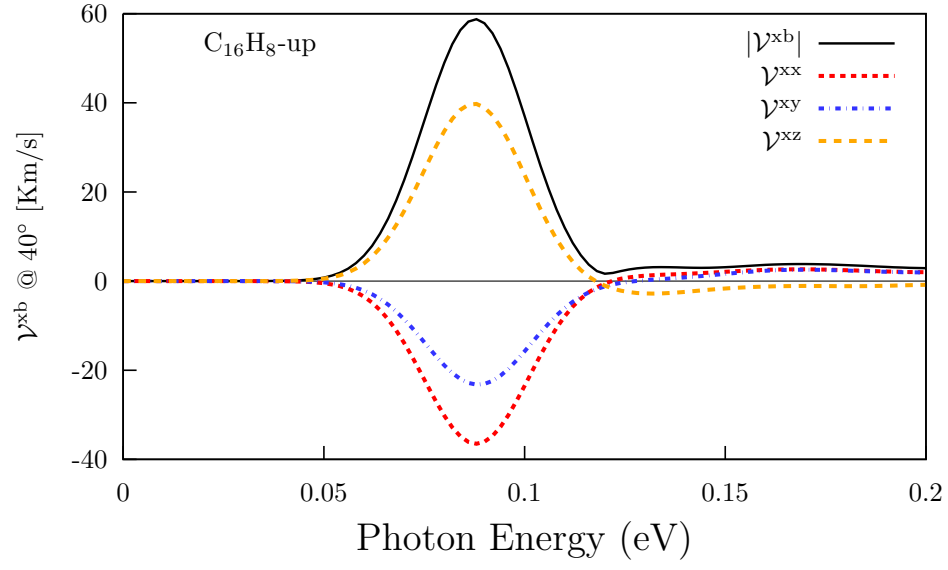


Figure 3: Three components of ν^{xb} @ 40° .

1.2 ν^{yb} energy range 0.0–0.2 eV

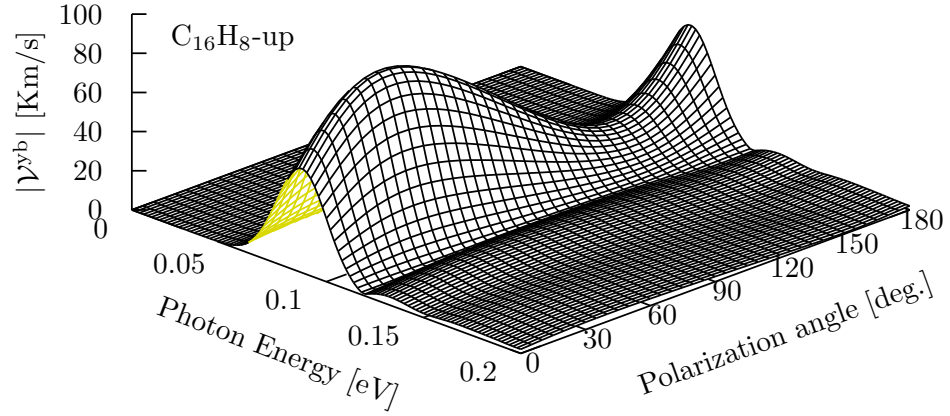


Figure 4: The most intense response for ν^{yb} is for 40° .

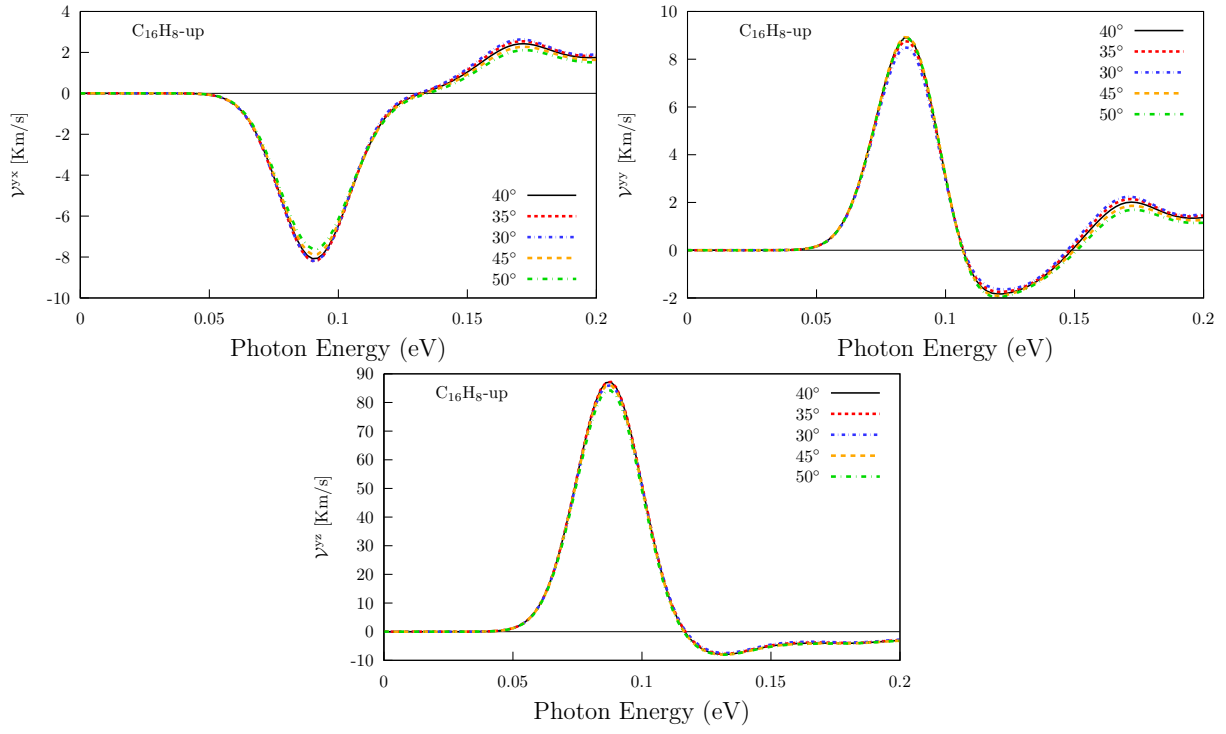


Figure 5: Cheking angle of incidence for y^b components.

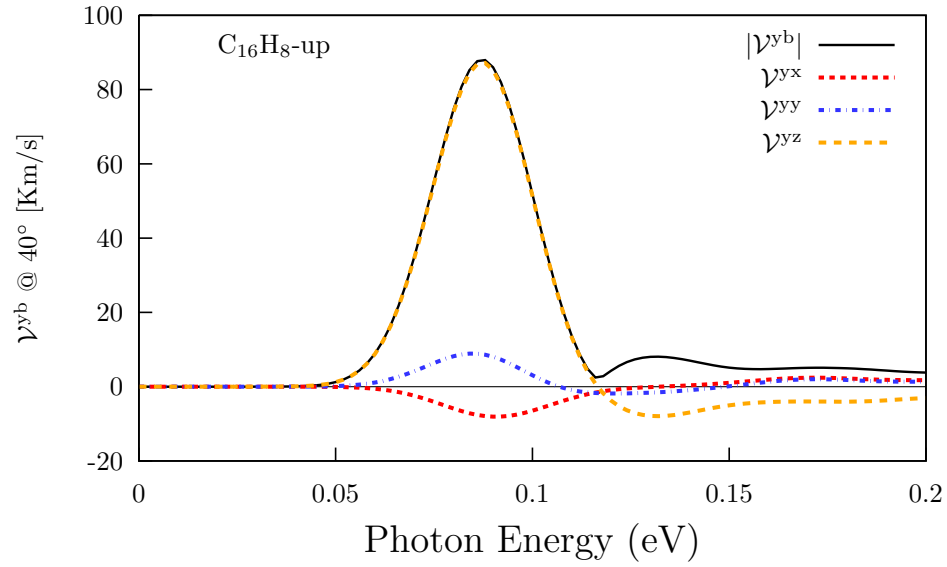


Figure 6: Three components of $\gamma^{yb} @ 40^\circ$.

1.3 \mathcal{V}^{xb} energy range 1.8–2.1 eV

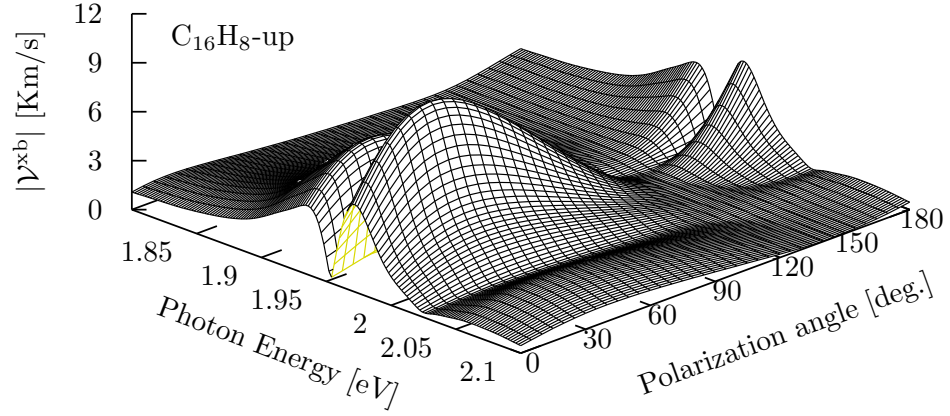


Figure 7: The most intense response for \mathcal{V}^{xb} is for 40° .

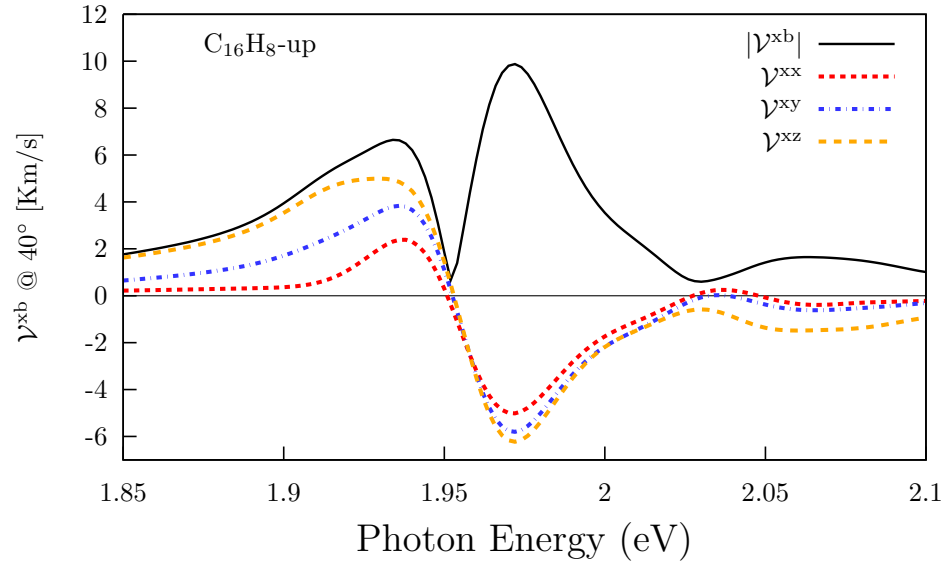


Figure 8: Three components of \mathcal{V}^{xb} @ 40° .

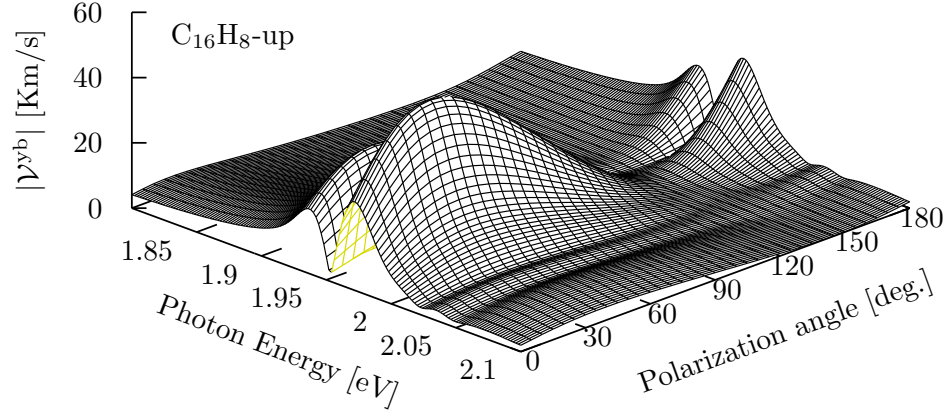


Figure 9: The most intense response for ν^{yb} is for 40° .

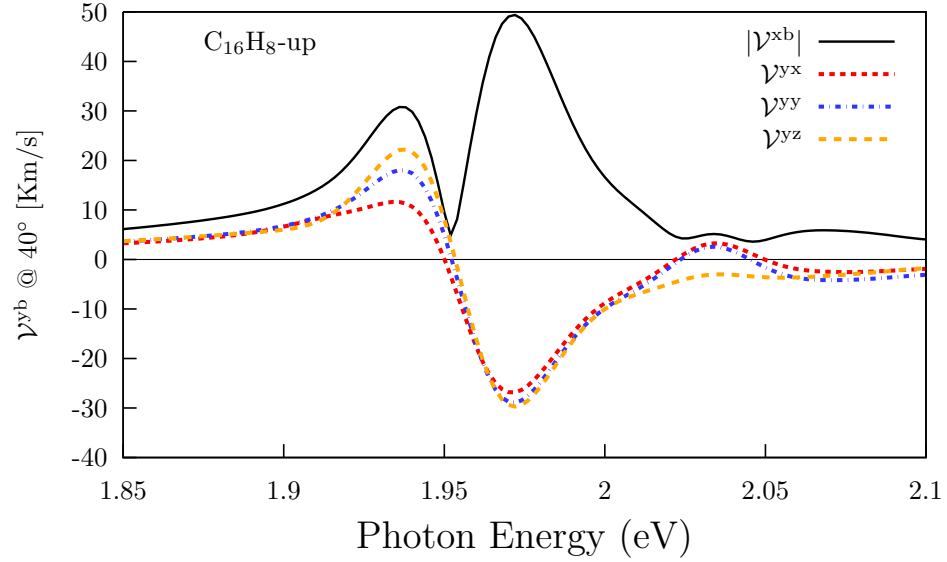


Figure 10: Three components of ν^{yb} @ 40° .

1.4 $|\mathcal{V}^{ab}|$, angles θ and φ , layers, and comparison with CdSe and GaAs for the energy range of 0.0–0.2 eV.

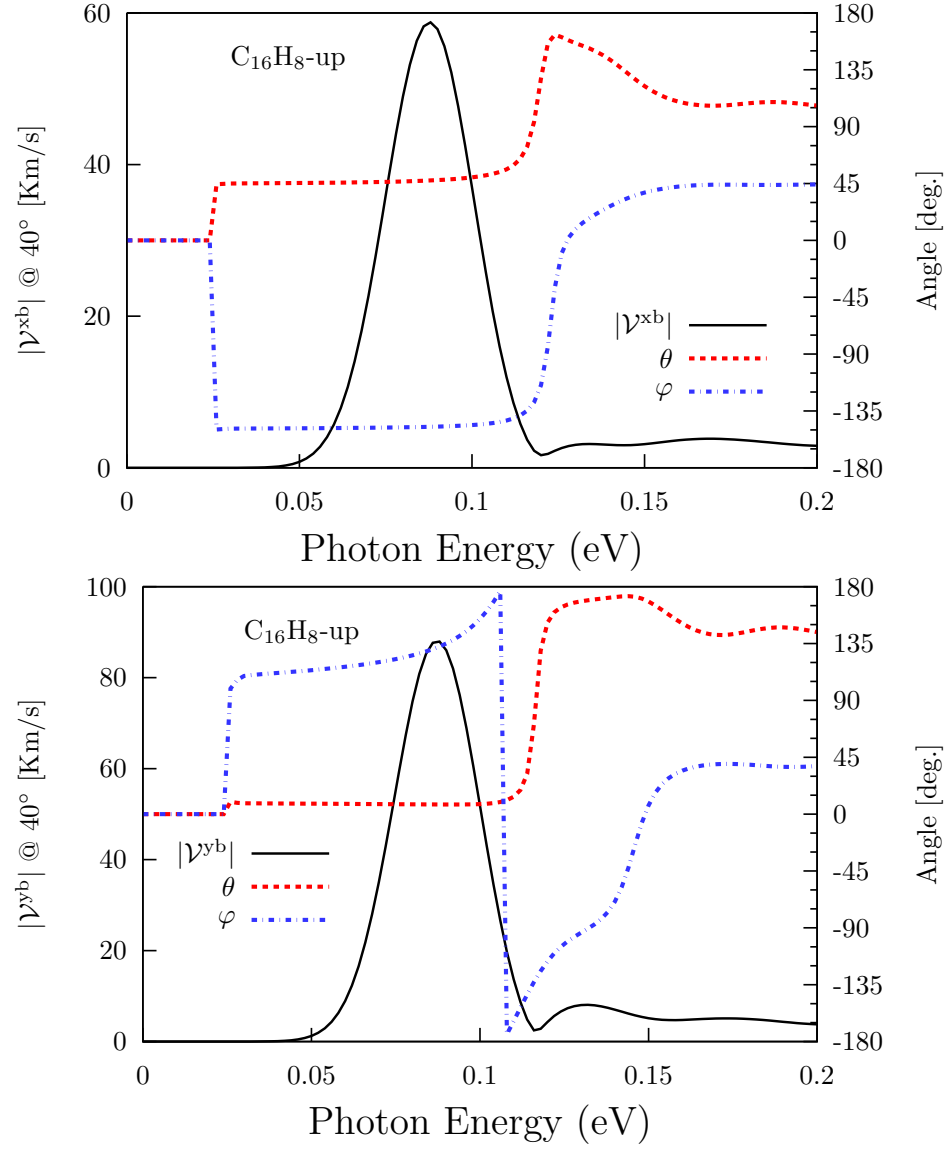


Figure 11: $|\mathcal{V}^{ab}|$ (solid line, leftside scale) and the corresponding angles θ and φ (dashed lines, rightside scale).

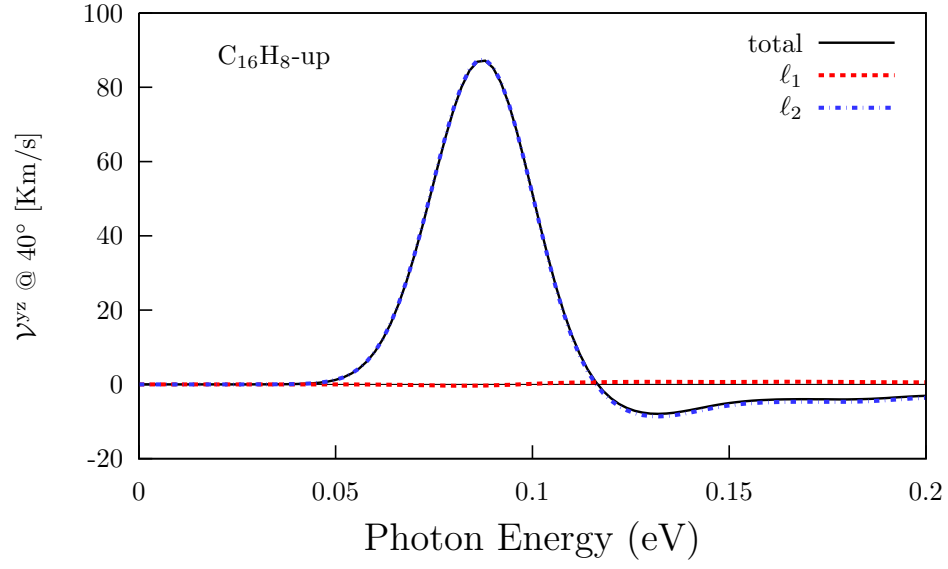


Figure 12: Layer decomposition for the most intense response: \mathcal{V}^{yz} .

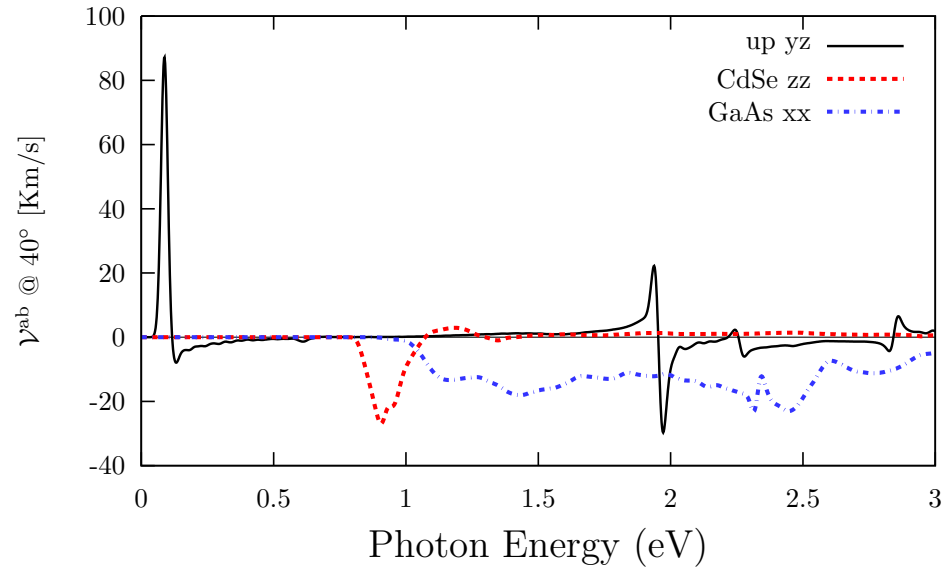


Figure 13: Comparisson of the most intense response vs the most intense responses of CdSe and GaAs.

1.5 $|\mathcal{V}^{ab}|$, angles θ and φ , layers, and comparison with CdSe and GaAs for the energy range of 1.8–2.1 eV

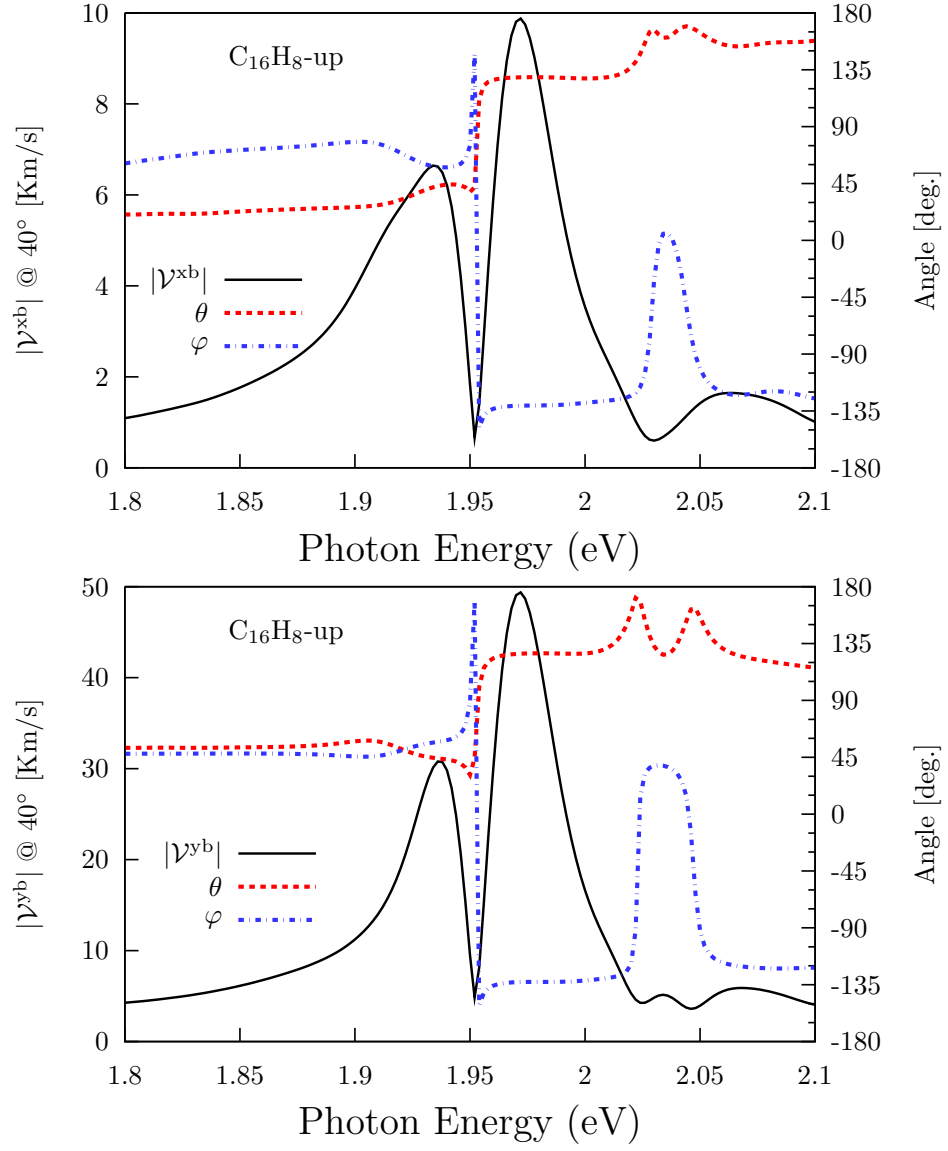


Figure 14: $|\mathcal{V}^{ab}|$ (solid line, leftside scale) and the corresponding angles θ and φ (dashed lines, rightside scale).

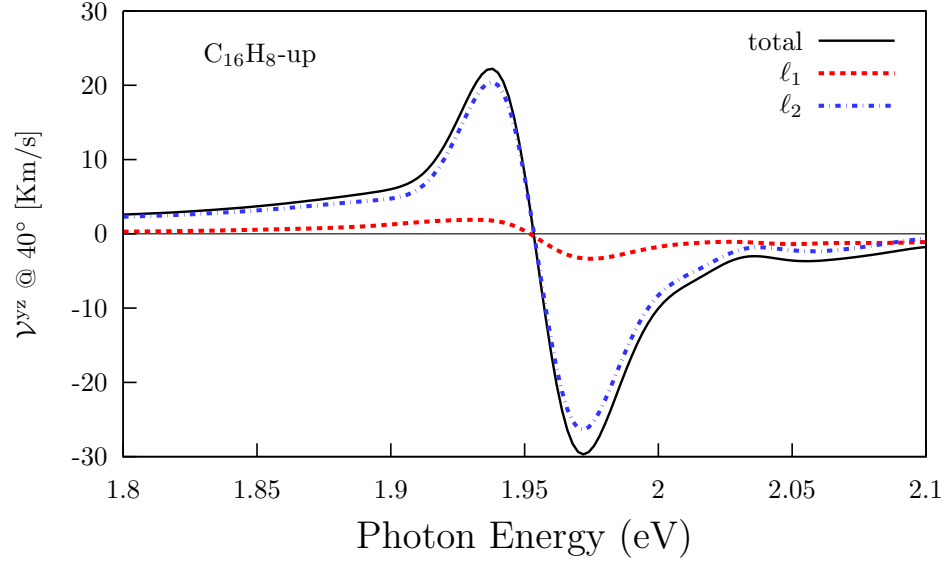


Figure 15: Layer decomposition for the most intense response: \mathcal{V}^{yz} .

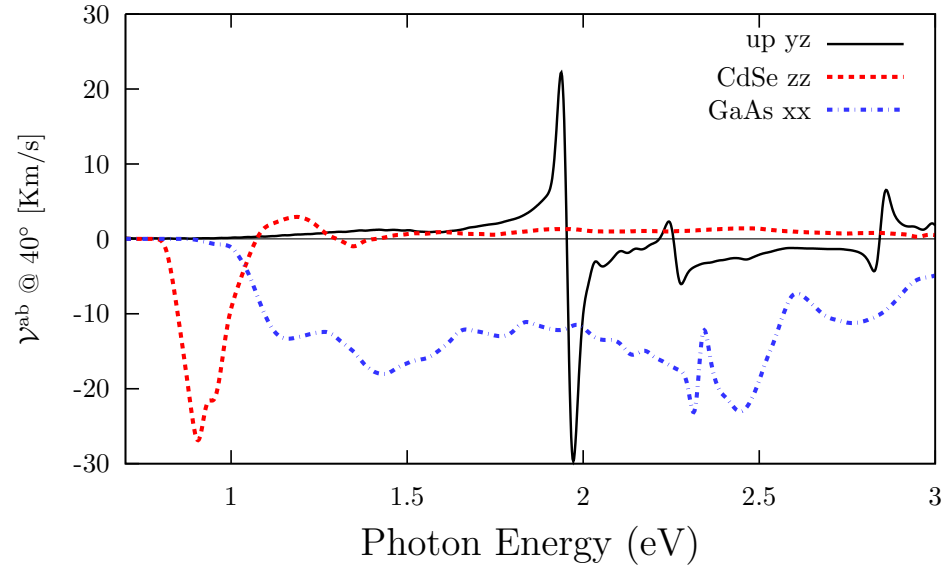


Figure 16: Comparisson of the most intense response vs the most intense responses of CdSe and GaAs.

2 alt

2.1 γ^{xb}

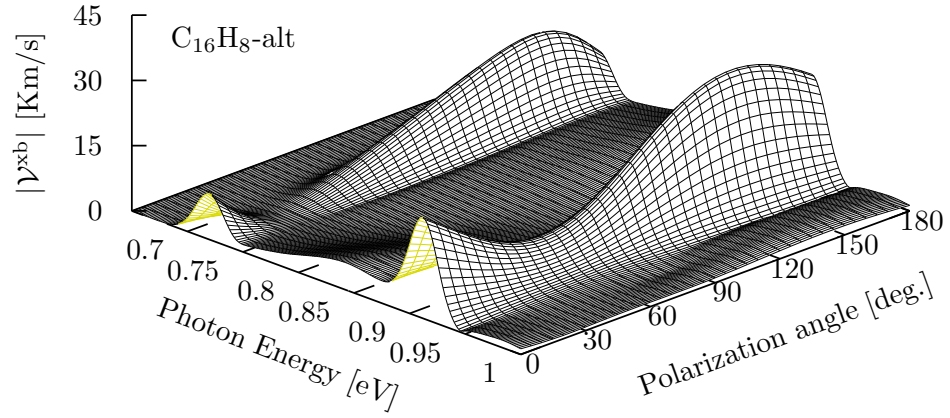


Figure 17: The most intense response for γ^{xb} is for 145° .

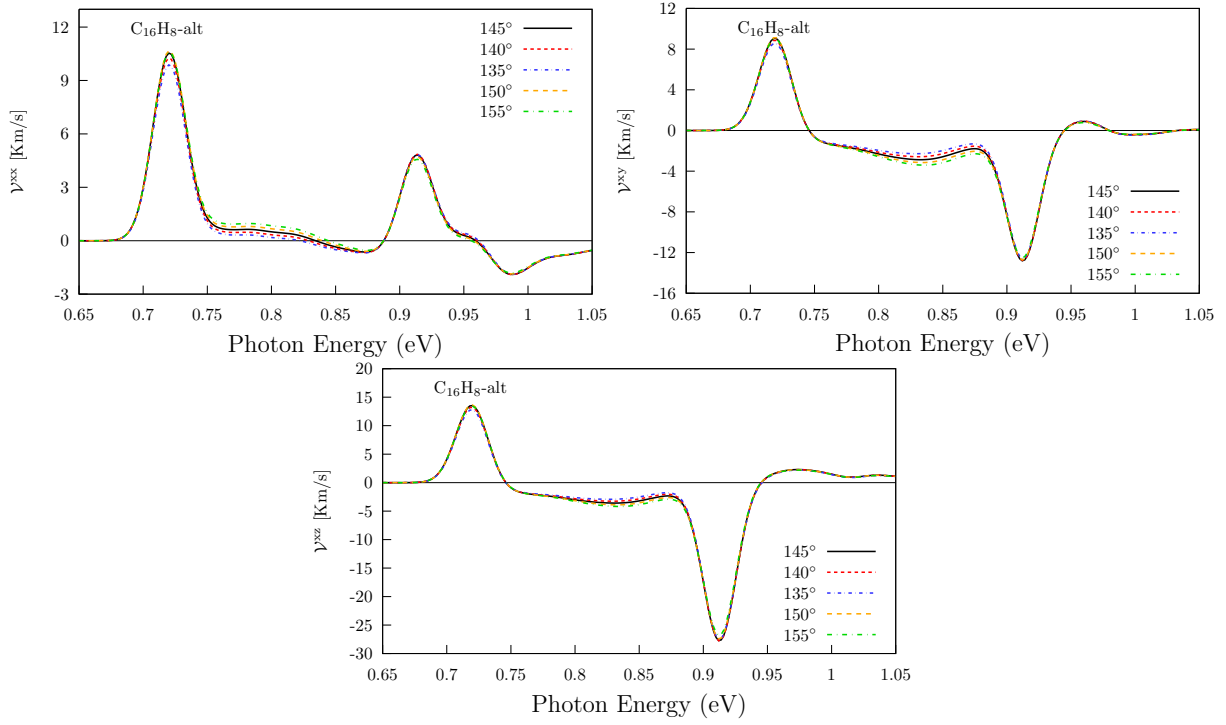


Figure 18: Cheking angle of incidence for xb components.

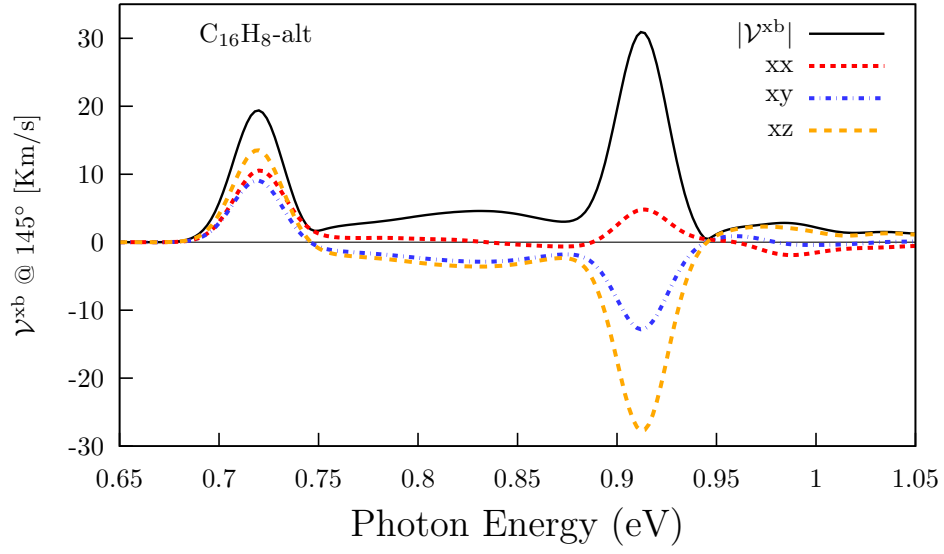


Figure 19: Three components of ν^{xb} @ 145° .

2.2 ν^{yb}

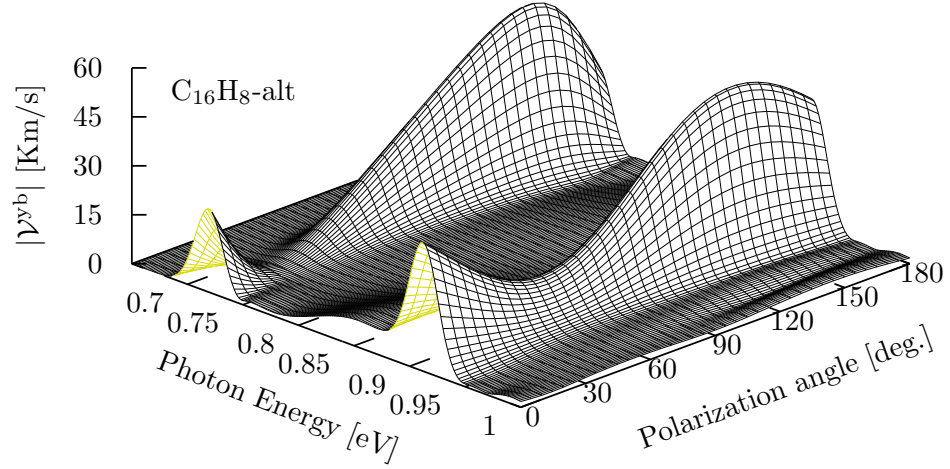


Figure 20: The most intense response for ν^{yb} is for 145° .

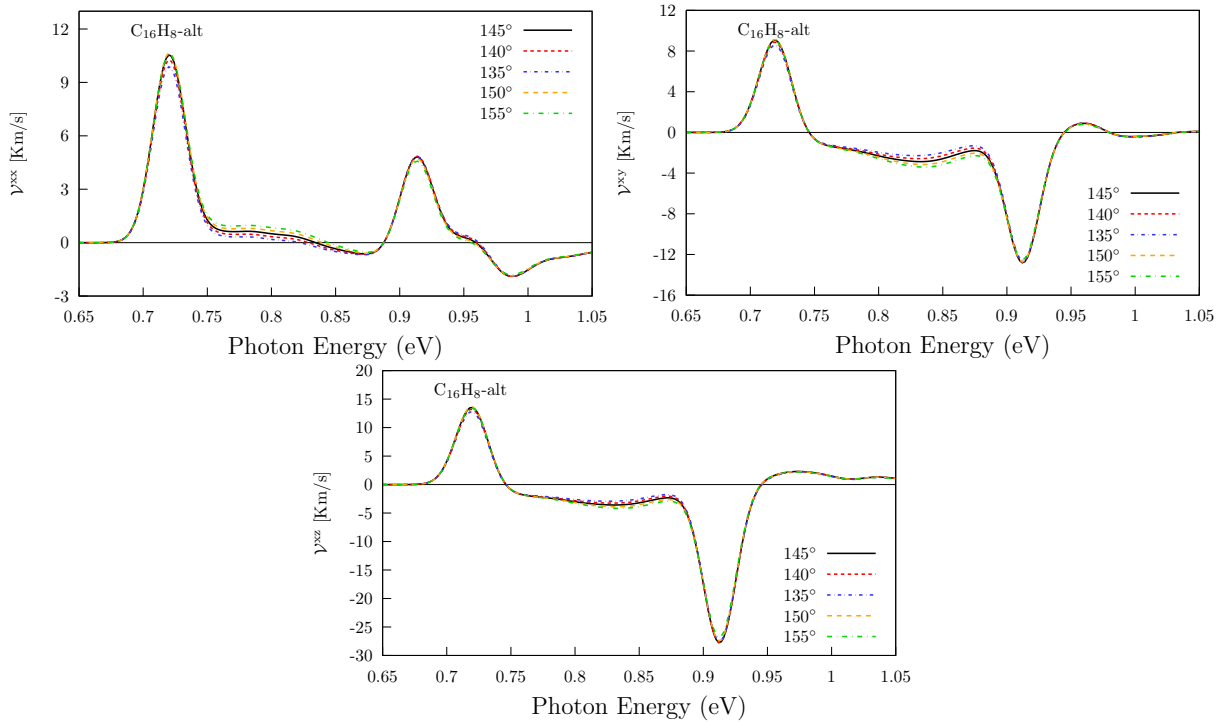


Figure 21: Cheking angle of incidence for y_b components.

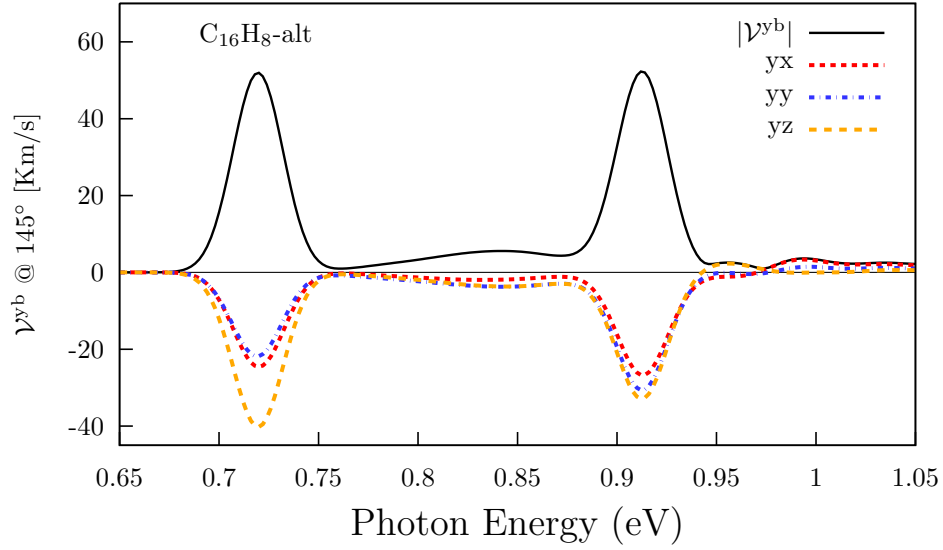


Figure 22: Three components of γ_{yb} @ 145°.

2.3 $|\mathcal{V}^{ab}|$, angles θ and φ , layers, and comparison with CdSe and GaAs.

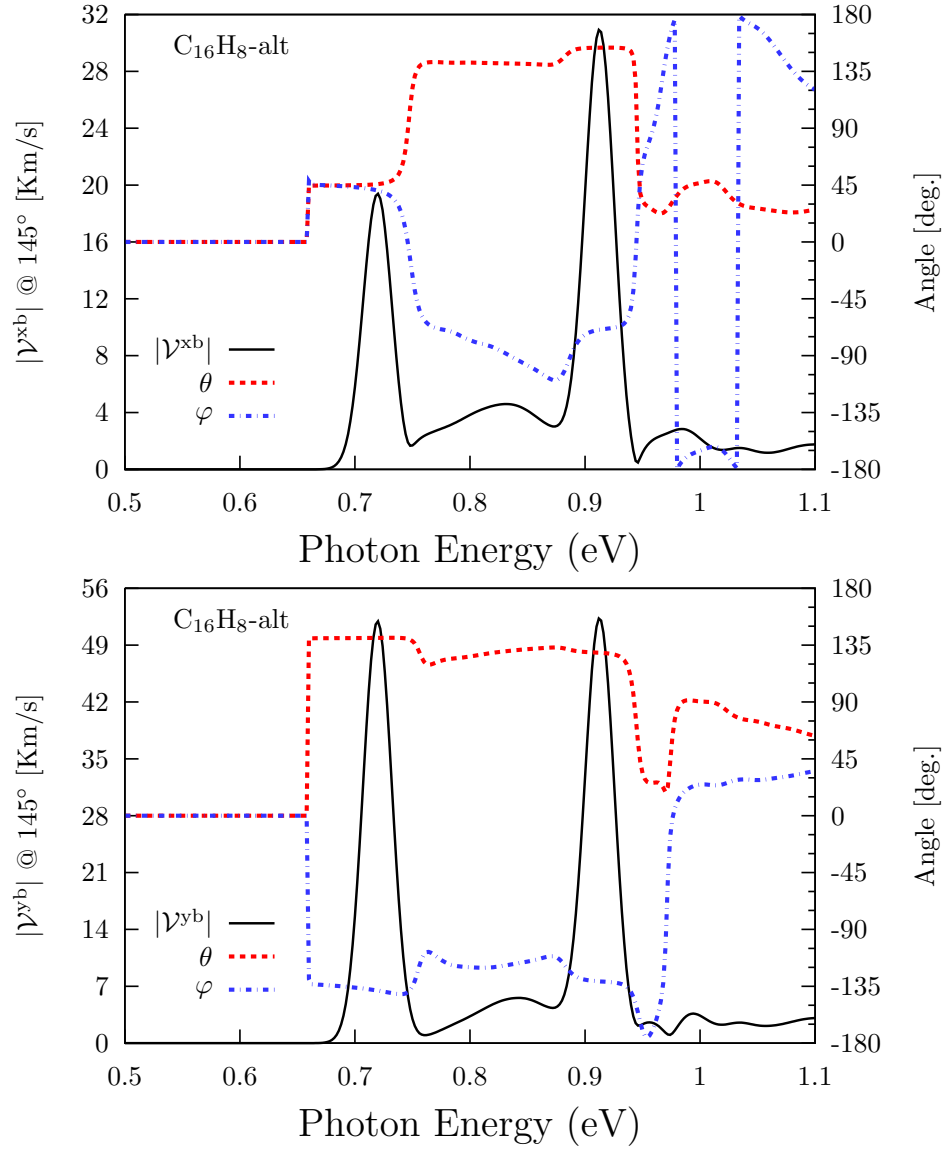


Figure 23: $|\mathcal{V}^{ab}|$ (solid line, leftside scale) and the corresponding angles θ and φ (dashed lines, rightside scale).

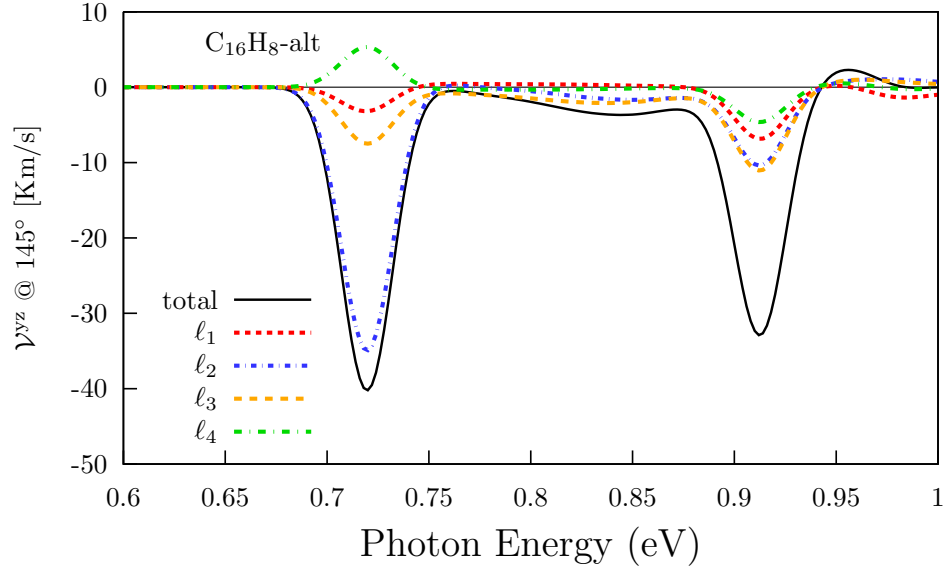


Figure 24: Layer decomposition for the most intense response: \mathcal{V}^{yz} .

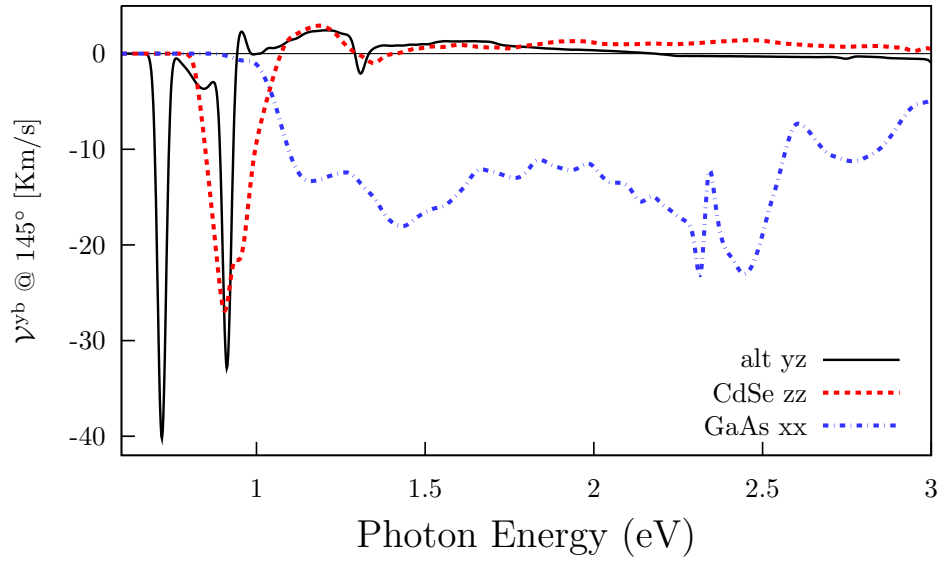


Figure 25: Comparisson of the most intense response vs the most intense responses of CdSe and GaAs.

3 aa

3.1 ν^{xb}

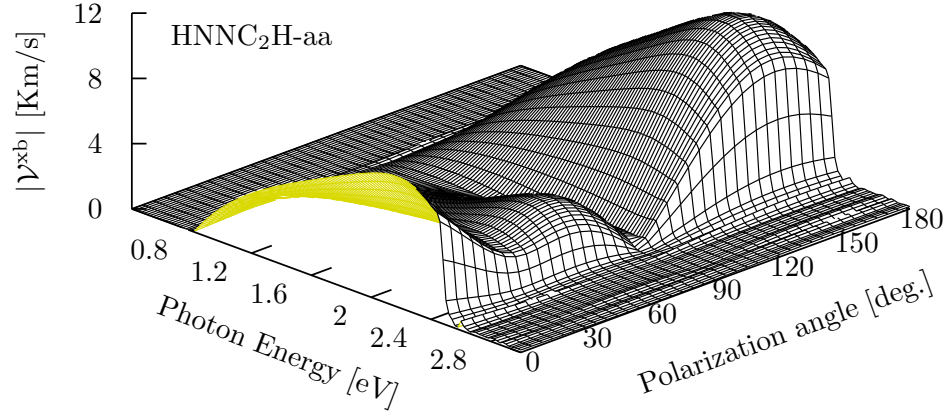


Figure 26: The most intense response for ν^{xb} is for 155° .

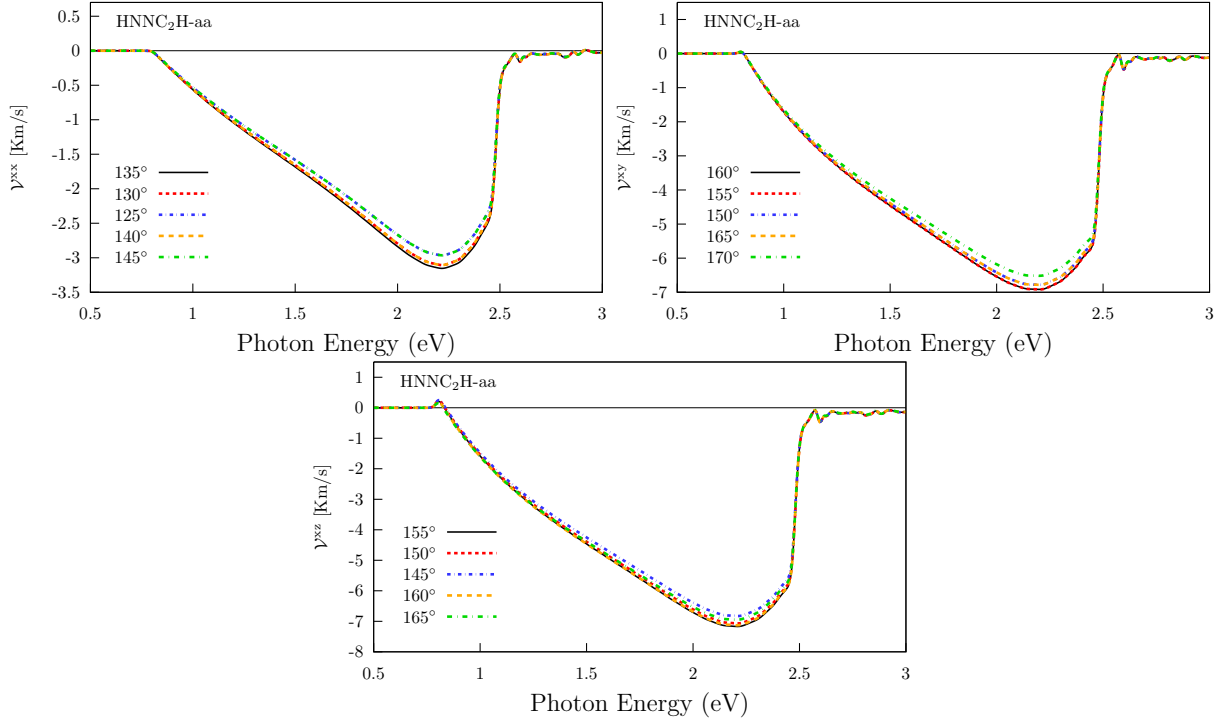


Figure 27: Cheking angle of incidence for xb components. There is a different angle for each component to have the most intense response.

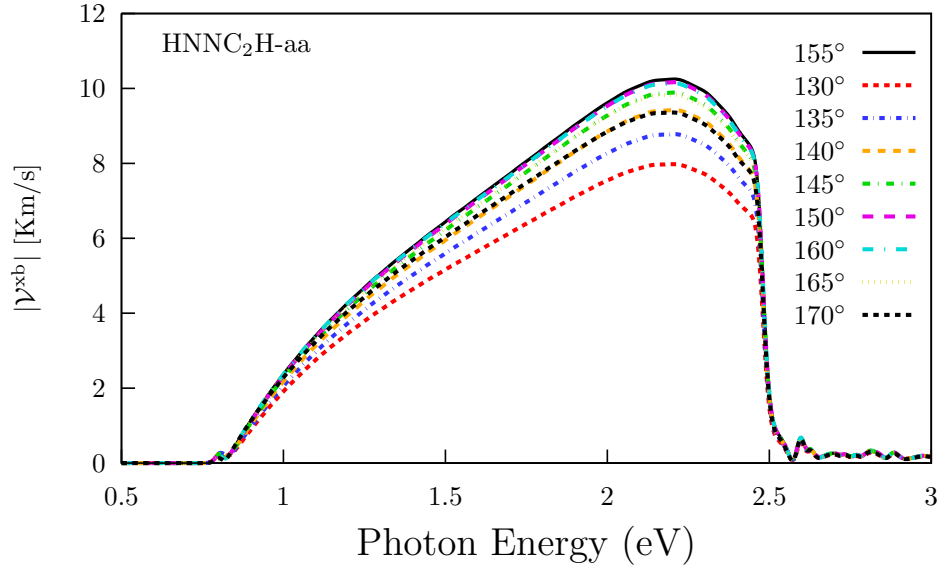


Figure 28: Comparisson of $|\mathcal{V}^{xb}|$ for different polarization angles.

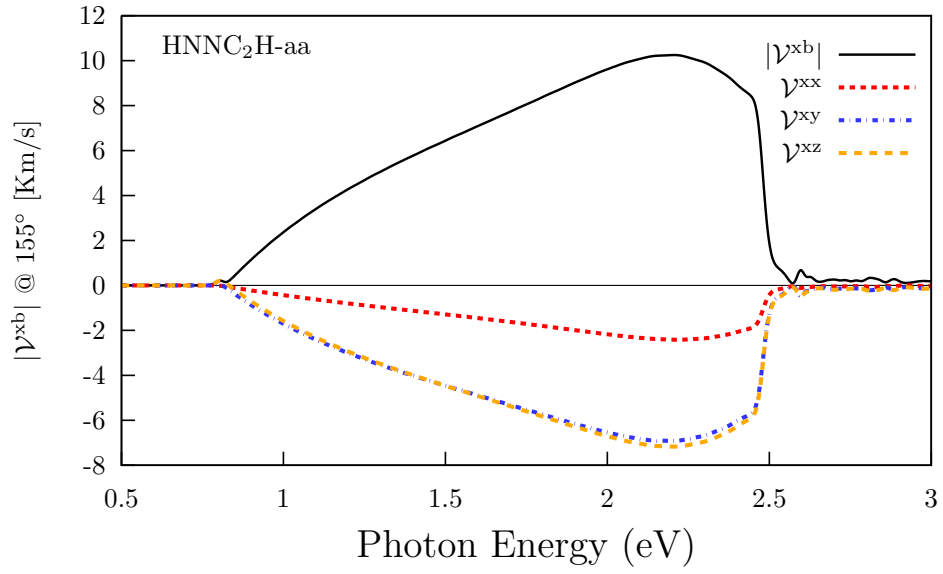


Figure 29: Three components of \mathcal{V}^{xb} @ 155° .

3.2 ν^{yb}

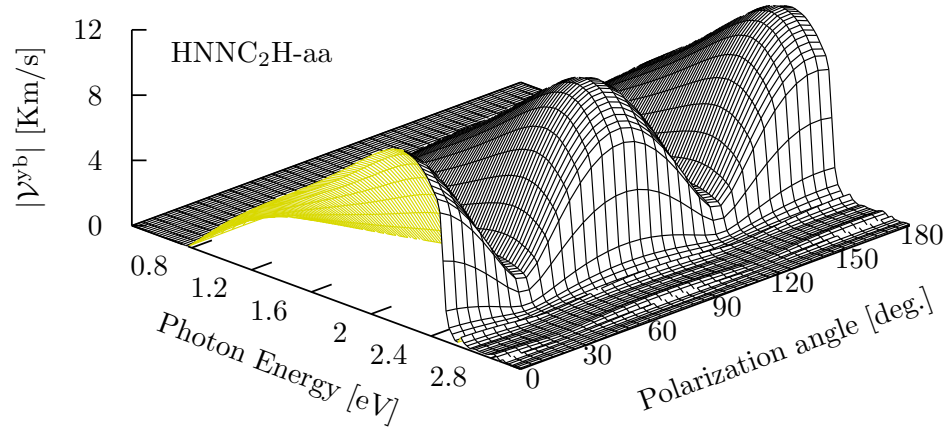


Figure 30: The most intense response for ν^{yb} is for 155°.

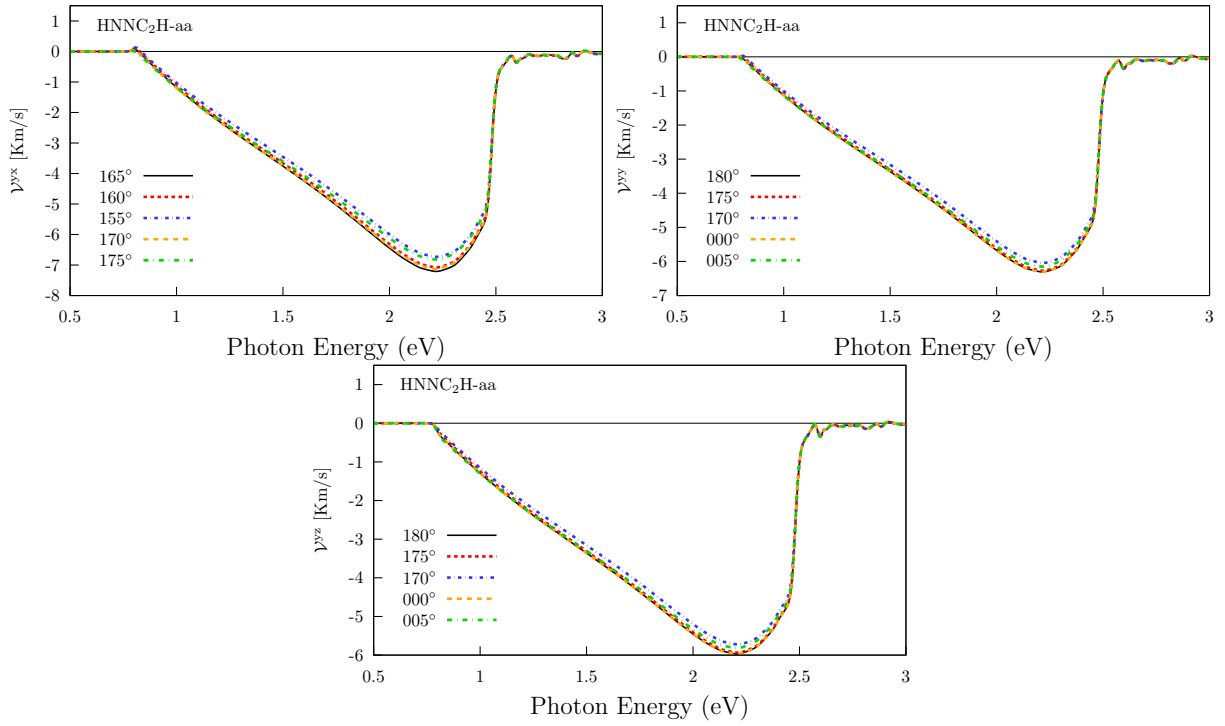


Figure 31: Checking angle of incidence for yb components. There is a different angle for each component to have the most intense response.

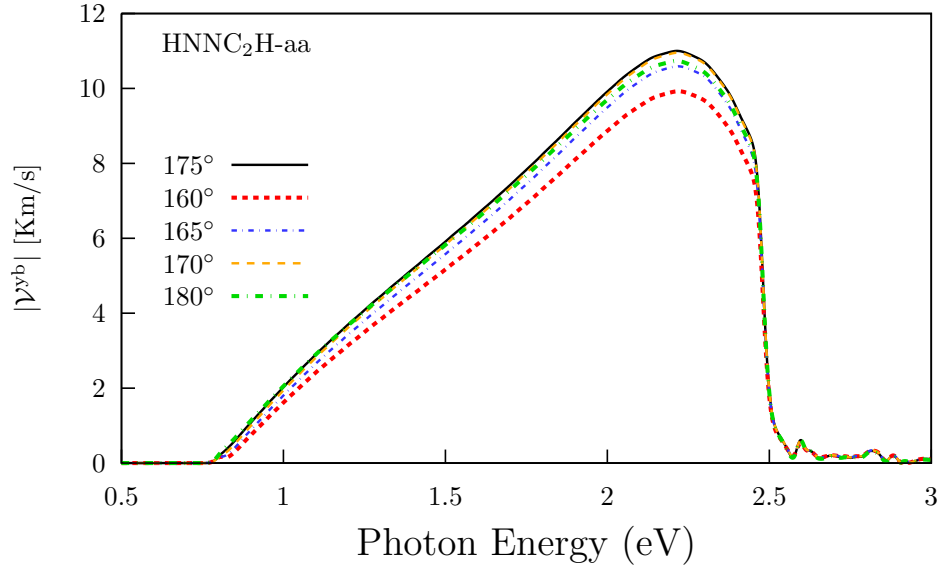


Figure 32: Comparisson of $|v^{yb}|$ for different polarization angles.

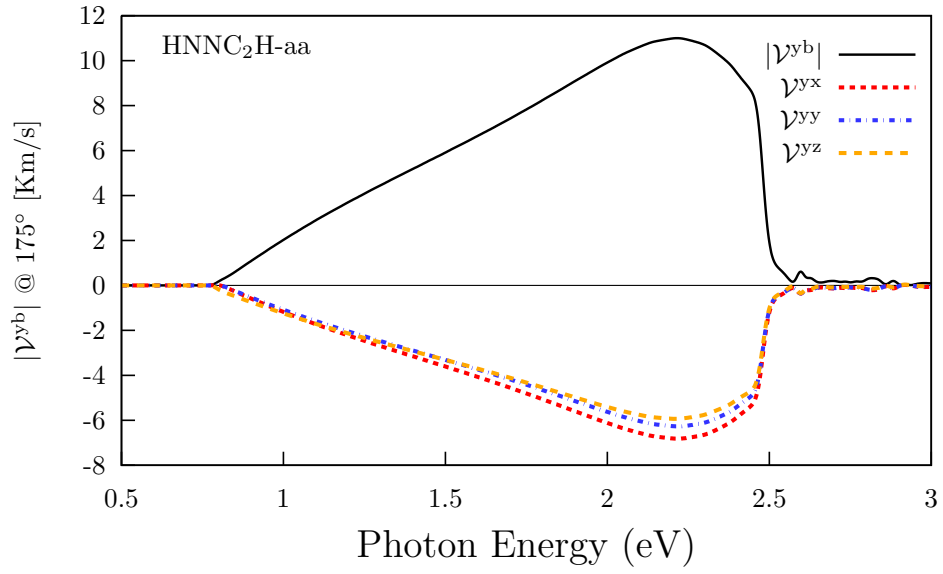


Figure 33: Three components of v^{yb} @ 175°.

3.3 $|\mathcal{V}^{ab}|$, angles θ and φ , layers, and comparison with CdSe and GaAs.

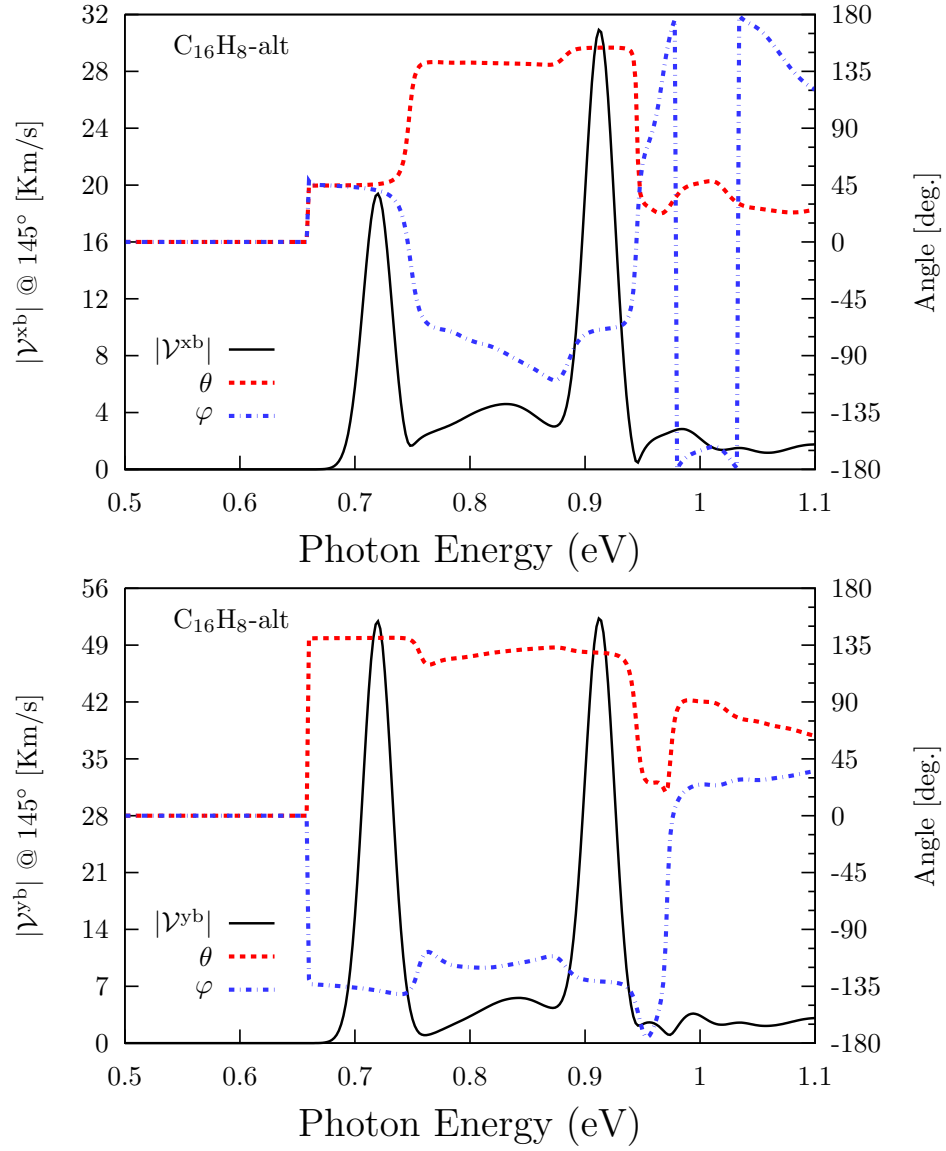


Figure 34: $|\mathcal{V}^{ab}|$ (solid line, leftside scale) and the corresponding angles θ and φ (dashed lines, rightside scale).

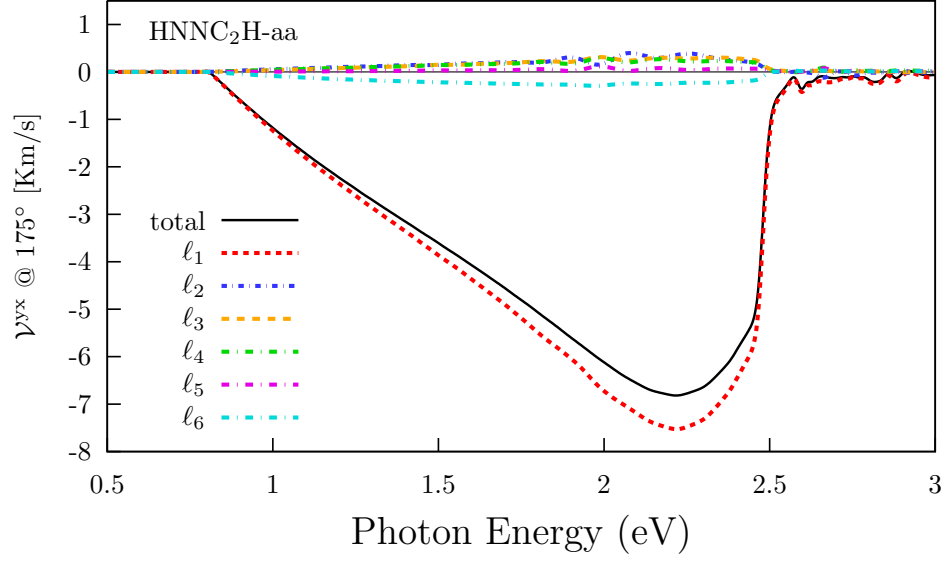


Figure 35: Layer decomposition for the most intense response: γ^{yz} .

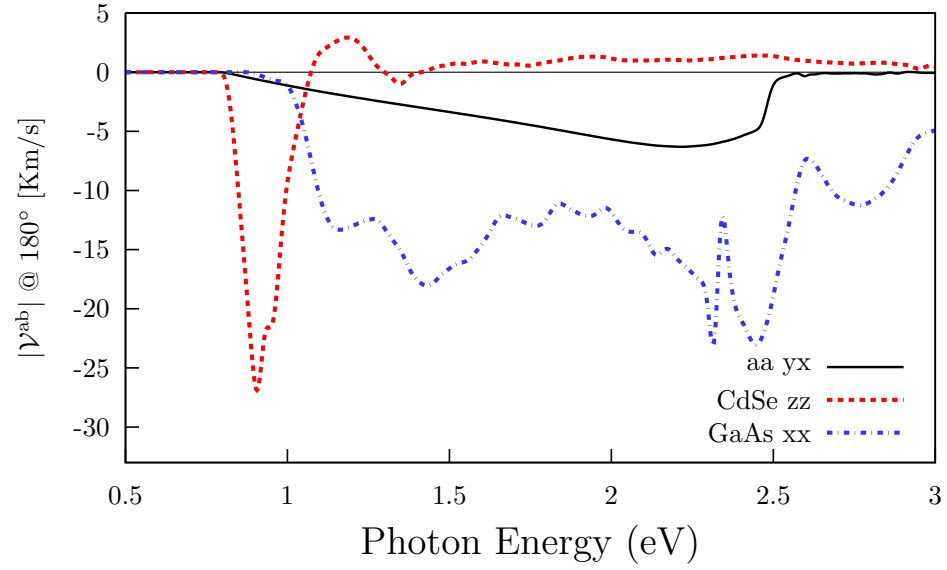


Figure 36: Comparisson of the most intense response vs the most intense responses of CdSe and GaAs.

4 ab

4.1 ν^{xb}

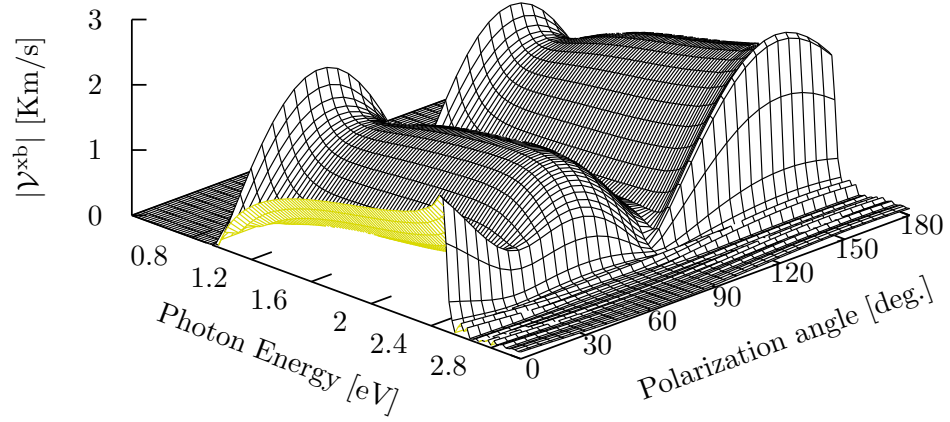


Figure 37: The most intense response for ν^{xb} is for 155° .

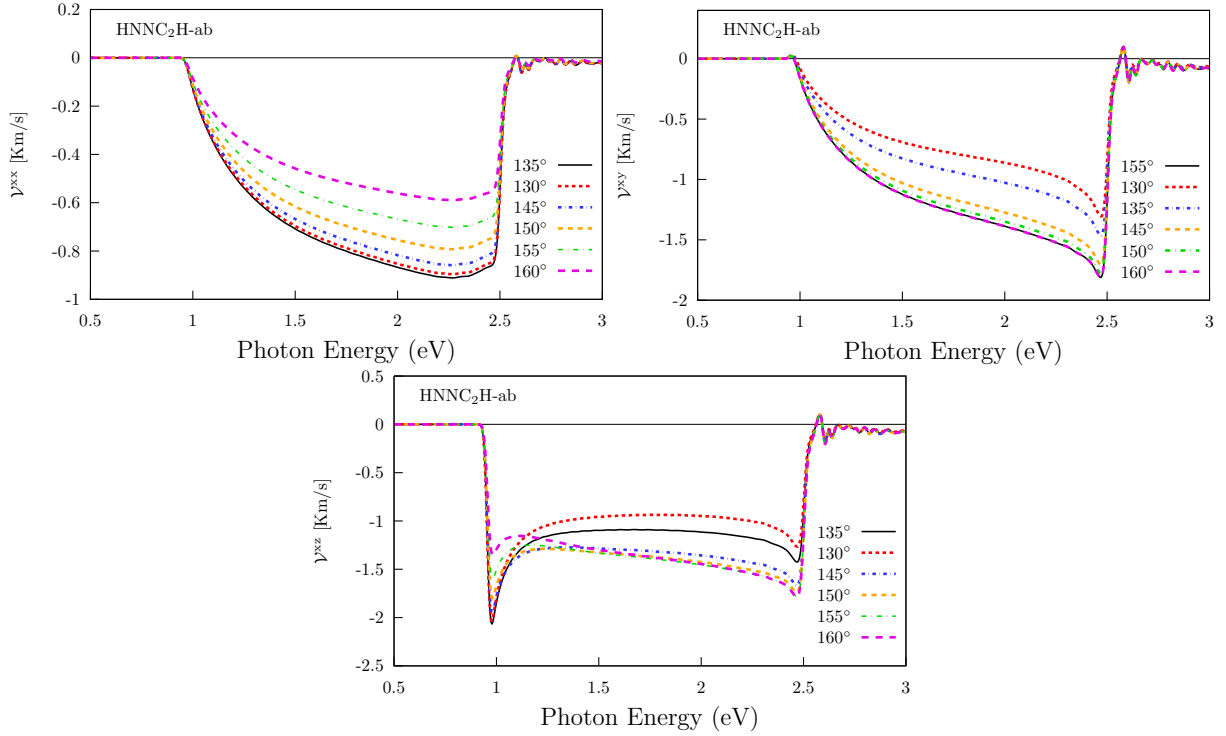


Figure 38: Cheking angle of incidence for xb components. There is a different angle for each component to have the most intense response.

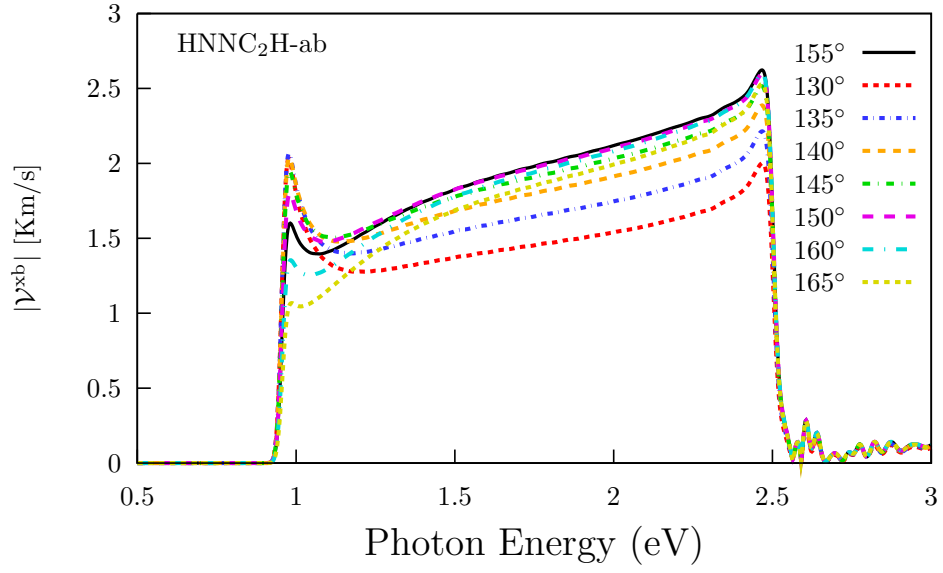


Figure 39: Comparisson of $|v^{xb}|$ for different polarization angles.

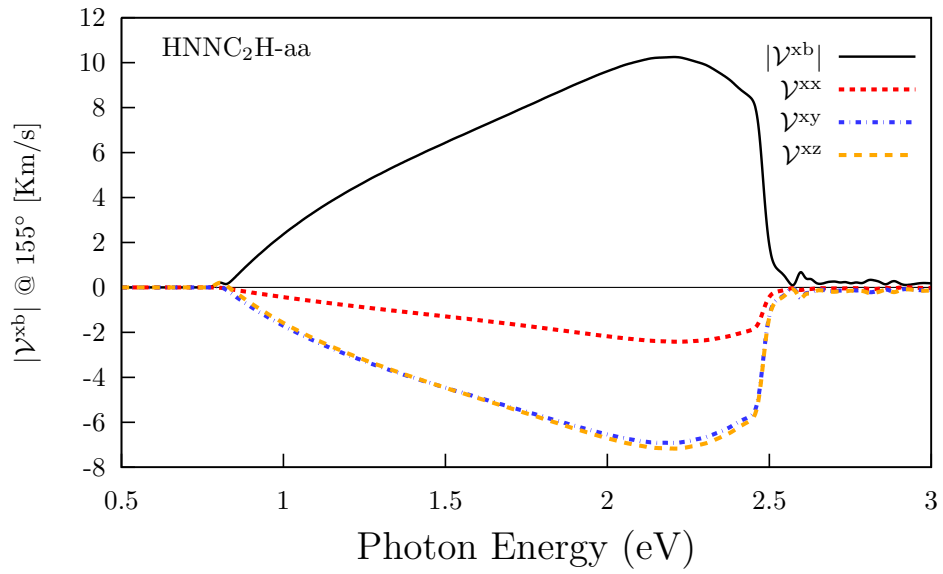


Figure 40: Three components of v^{xb} @ 155° .

4.2 ν^{yb}

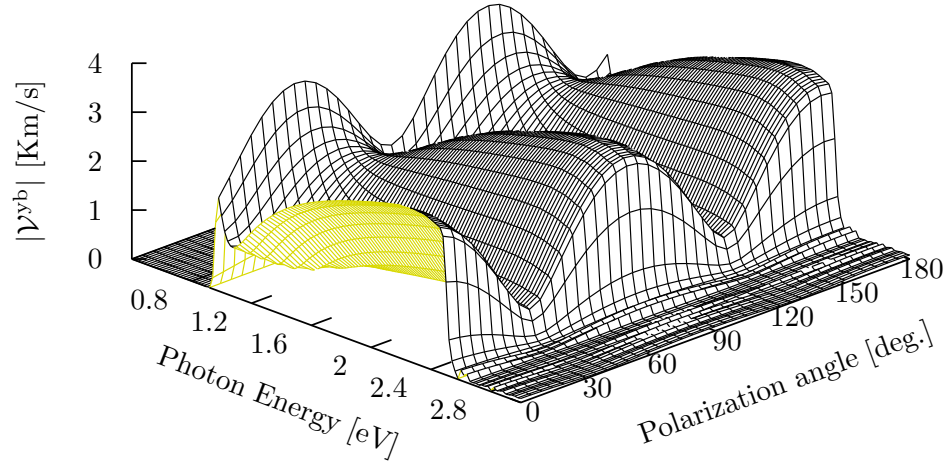


Figure 41: The most intense response for ν^{yb} is for 155° .

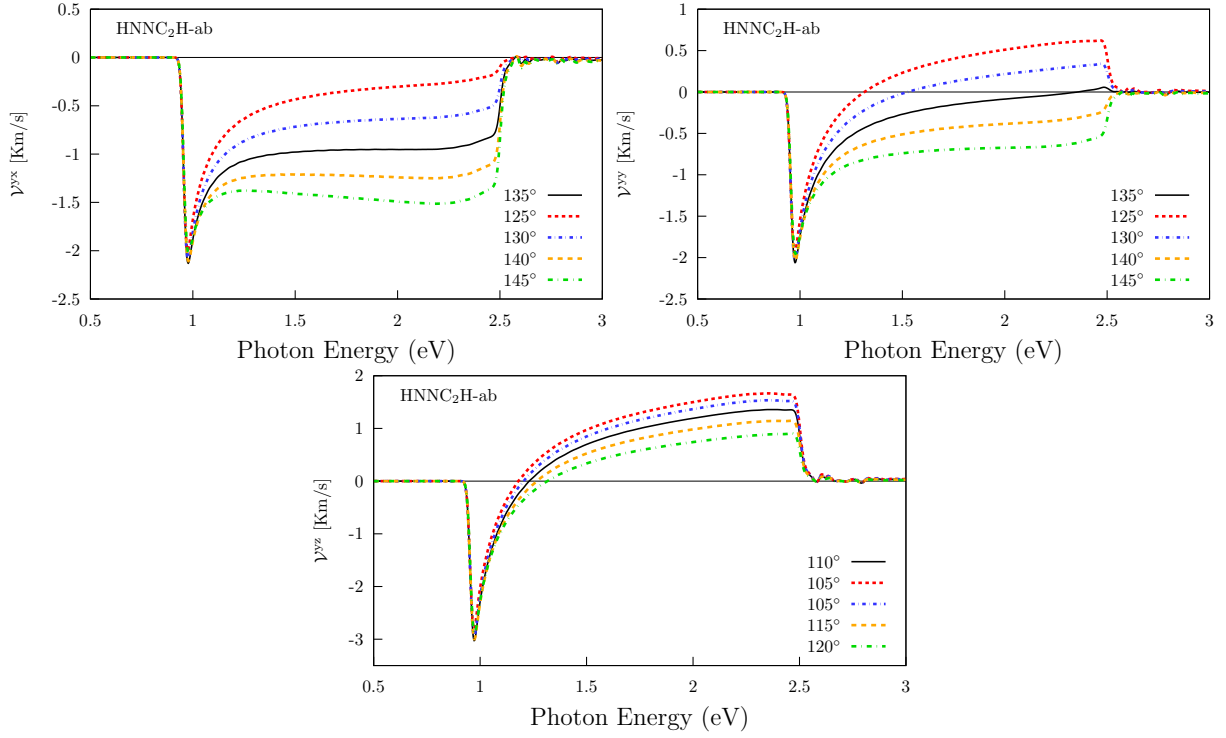


Figure 42: Cheking angle of incidence for yb components. There is a different angle for each component to have the most intense response.

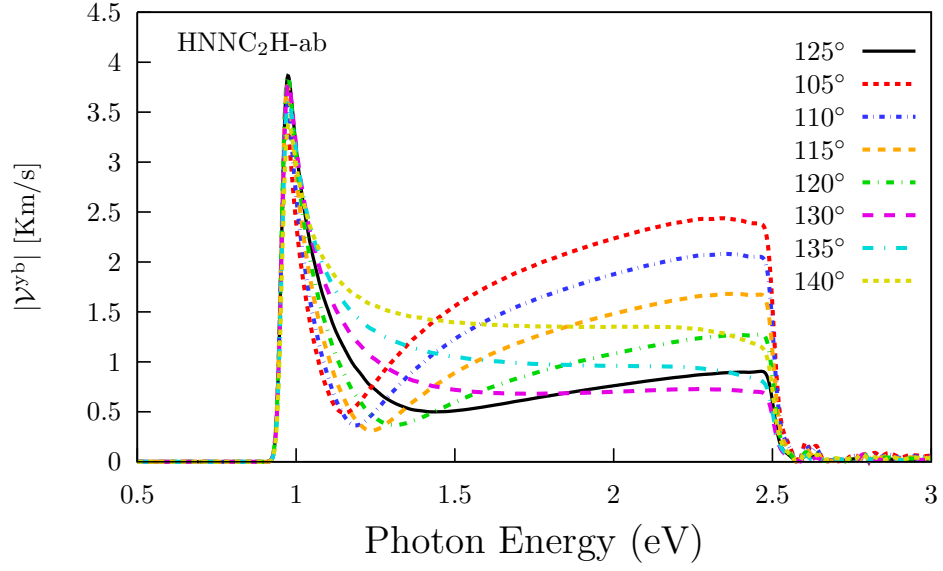


Figure 43: Comparisson of $|\mathcal{V}^{yb}|$ for different polarization angles.

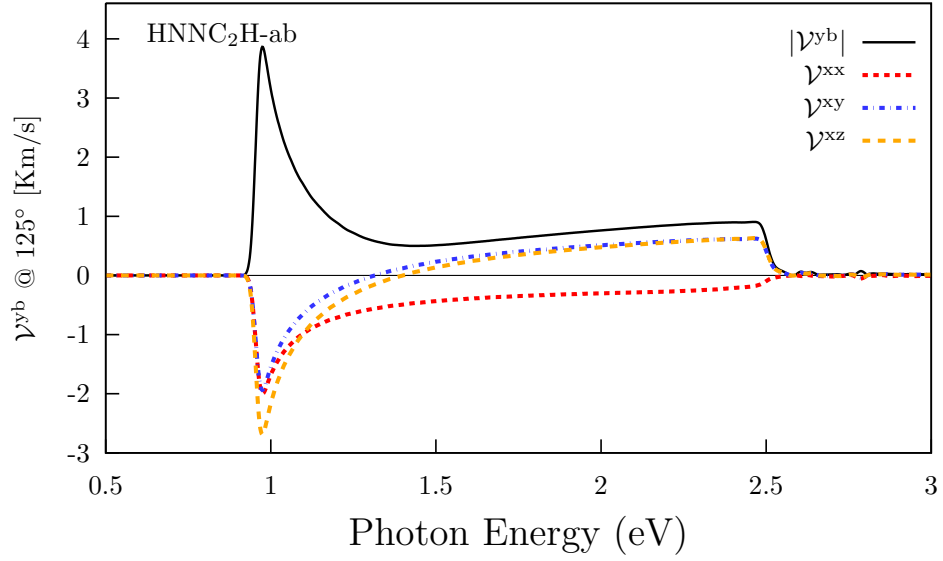


Figure 44: Three components of \mathcal{V}^{yb} @ 125° .

4.3 $|\mathcal{V}^{ab}|$, angles θ and φ , layers, and comparison with CdSe and GaAs.

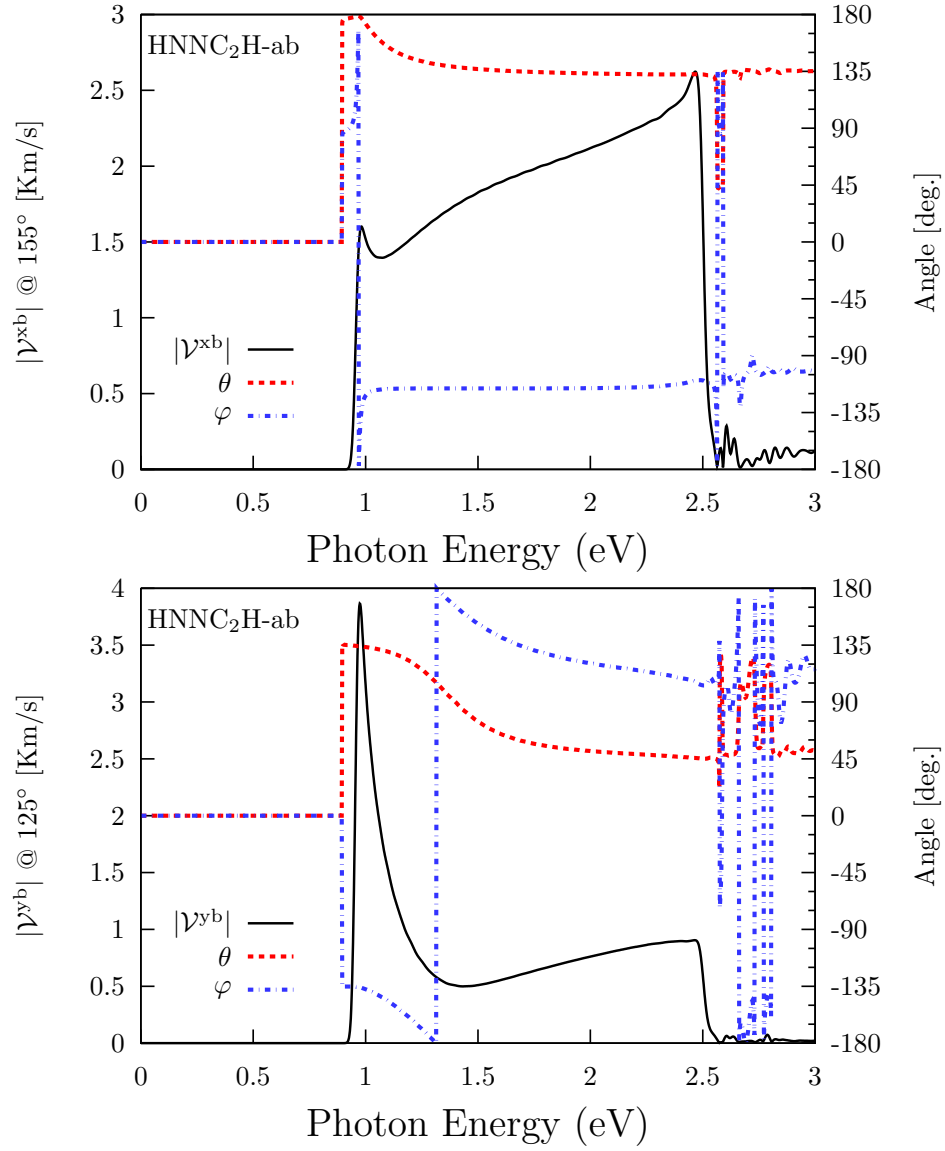


Figure 45: $|\mathcal{V}^{ab}|$ (solid line, leftside scale) and the corresponding angles θ and φ (dashed lines, rightside scale).

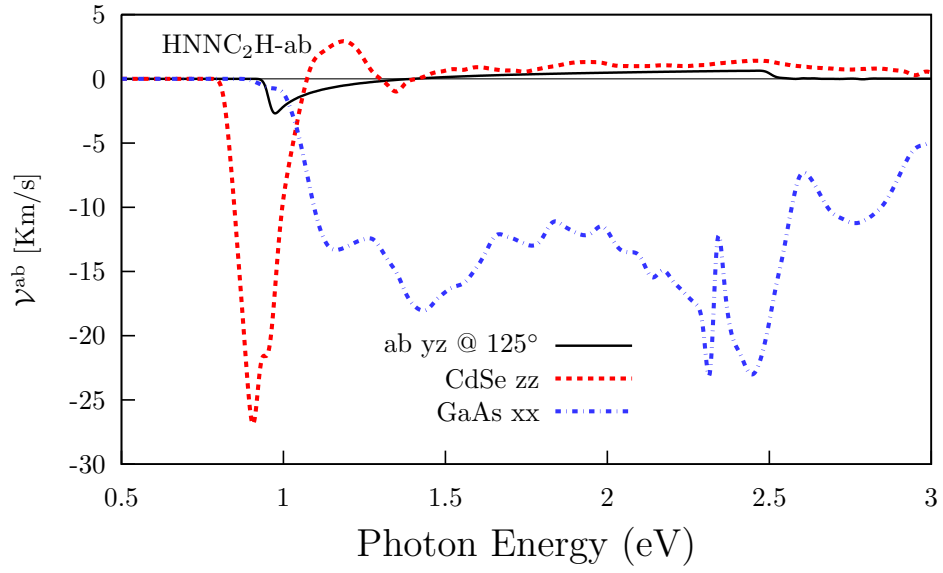


Figure 46: Comparisson of the most intense response vs the most intense responses of CdSe and GaAs.